TOSHIBA Photocoupler GaAlAs Ired & Photo−IC

TLP250

Transistor Inverter
Inverter For Air Conditionor
IGBT Gate Drive
Power MOS FET Gate Drive

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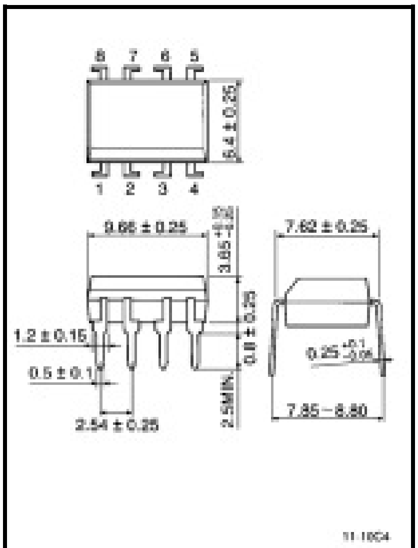
Unit in mm



TOSHIBA 11−10C4
Weight: 0.54 g

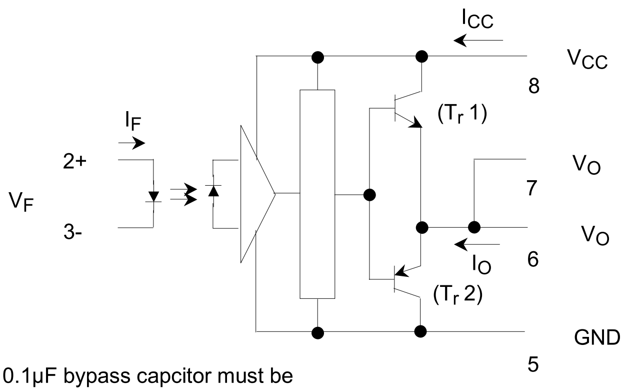
The TOSHIBA TLP250 consists of a GaAlAs light emitting diode and a integrated photodetector.
This unit is 8−lead DIP package.
TLP250 is suitable for gate driving circuit of IGBT or power MOS FET.

- Input threshold current: I_F=5mA(max.)
- Supply current (I_{CC}): 11mA(max.)
- Supply voltage (V_{CC}): 10−35V
- Output current (I_O): ±1.5A (max.)
- Switching time (t_{pLH}/t_{pHL}): 1.5μs(max.)
- Isolation voltage: 2500V_{rms}(min.)
- UL recognized: UL1577, file No.E67349
- Option (D4) type
  VDE approved: DIN VDE0884/06.92,certificate No.76823
  Maximum operating insulation voltage: 630V_{PK}
  Highest permissible over voltage: 4000V_{PK}

(Note) When a VDE0884 approved type is needed, please designate the "option (D4)"

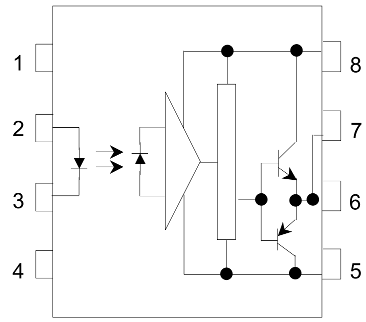
- Creepage distance: 6.4mm(min.)
  Clearance: 6.4mm(min.)

Schmatic



A 0.1μF bypass capcitor must be connected between pin 8 and 5 (See Note 5).

Pin Configuration (top view)



1 : N.C.
2 : Anode
3 : Cathode
4 : N.C.
5 : GND
6 : V_O (Output)
7 : V_O
8 : V_{CC}

Truth Table

		Tr1	Tr2
Input LED	On	On	Off
	Off	Off	On

Absolute Maximum Ratings (Ta = 25°C)

	Characteristic		Symbol	Rating	Unit
LED	Forward current		I_F	20	mA
	Forward current derating (Ta ≥ 70°C)		ΔI_F / ΔTa	−0.36	mA / °C
	Peak transient forward curent (Note 1)		I_{FPT}	1	A
	Reverse voltage		V_R	5	V
	Junction temperature		Tj	125	°C
Detector	"H"peak output current (P_W ≤ 2.5μs,f ≤ 15kHz) (Note 2)		I_{OPH}	−1.5	A
	"L"peak output current (P_W ≤ 2.5μs,f ≤ 15kHz) (Note 2)		I_{OPL}	+1.5	A
	Output voltage	(Ta ≤ 70°C)	V_O	35	V
		(Ta = 85°C)		24	
	Supply voltage	(Ta ≤ 70°C)	V_{CC}	35	V
		(Ta = 85°C)		24	
	Output voltage derating (Ta ≥ 70°C)		ΔV_O / ΔTa	−0.73	V / °C
	Supply voltage derating (Ta ≥ 70°C)		ΔV_{CC} / ΔTa	−0.73	V / °C
	Junction temperature		Tj	125	°C
Operating frequency (Note 3)			f	25	kHz
Operating temperature range			T_{opr}	−20~85	°C
Storage temperature range			T_{stg}	−55~125	°C
Lead soldering temperature (10 s) (Note 4)			T_{sol}	260	°C
Isolation voltage (AC, 1 min., R.H.≤ 60%) (Note 5)			BV_S	2500	Vrms

Note 1: Pulse width P_W ≤ 1μs, 300pps

Note 2: Exporenential wavefom

Note 3: Exporenential wavefom, I_{OPH} ≤ −1.0A(≤ 2.5μs), I_{OPL} ≤ +1.0A(≤ 2.5μs)

Note 4: It is 2 mm or more from a lead root.

Note 5: Device considerd a two terminal device: Pins 1, 2, 3 and 4 shorted together, and pins 5, 6, 7 and 8 shorted together.

Note 6: A ceramic capacitor(0.1μF) should be connected from pin 8 to pin 5 to stabilize the operation of the high gain linear amplifier. Failure to provide the bypassing may impair the switching property. The total lead length between capacitor and coupler should not exceed 1cm.

Recommended Operating Conditions

Characteristic	Symbol	Min.	Typ.	Max.		Unit
Input current, on (Note 7)	$I_{F(ON)}$	7	8	10		mA
Input voltage, off	$V_{F(OFF)}$	0	—	0.8		V
Supply voltage	V_{CC}	15	—	30	20	V
Peak output current	I_{OPH}/I_{OPL}	—	—	±0.5		A
Operating temperature	T_{opr}	−20	25	70	85	°C

Note 7: Input signal rise time (fall time) < 0.5 μs.

Electrical Characteristics (Ta = −20~70°C, unless otherwise specified)

Characteristic		Symbol	Test Circuit	Test Condition		Min.	Typ.*	Max.	Unit
Input forward voltage		V_F	—	I_F = 10 mA , Ta = 25°C			1.6	1.8	V
Temperature coefficient of forward voltage		ΔV_F / ΔTa	—	I_F = 10 mA		—	−2.0	—	mV / °C
Input reverse current		I_R	—	V_R = 5V, Ta = 25°C			—	10	μA
Input capacitance		C_T	—	V = 0 , f = 1MHz , Ta = 25°C		—	45	250	pF
Output current	"H" level	I_{OPH}	3	V_{CC} = 30V (*1)	I_F = 10 mA V_{8-6} = 4V	−0.5	−1.5	—	A
	"L" level	I_{OPL}	2		I_F = 0 V_{6-5} = 2.5V	0.5	2	—	
Output voltage	"H" level	V_{OH}	4	V_{CC1} = +15V, V_{EE1} = −15V R_L = 200Ω, I_F = 5mA		11	12.8	—	V
	"L" level	V_{OL}	5	V_{CC1} = +15V, V_{EE1} = −15V R_L = 200Ω, V_F = 0.8V		—	−14.2	−12.5	
Supply current	"H" level	I_{CCH}	—	V_{CC} = 30V, I_F = 10mA Ta = 25°C		—	7	—	mA
				V_{CC} = 30V, I_F = 10mA		—	—	11	
	"L" level	I_{CCL}	—	V_{CC} = 30V, I_F = 0mA Ta = 25°C		—	7.5	—	
				V_{CC} = 30V, I_F = 0mA		—	—	11	
Threshold input current	"Output L→H"	I_{FLH}	—	V_{CC1} = +15V, V_{EE1} = −15V R_L = 200Ω, V_O > 0V		—	1.2	5	mA
Threshold input voltage	"Output H→L"	I_{FHL}	—	V_{CC1} = +15V, V_{EE1} = −15V R_L = 200Ω, V_O < 0V		0.8	—	—	V
Supply voltage		V_{CC}	—			10	—	35	V
Capacitance (input–output)		C_S	—	V_S = 0 , f = 1MHz Ta = 25ꆒ		—	1.0	2.0	pF
Resistance(input–output)		R_S	—	V_S = 500V , Ta = 25°C R.H.≤ 60%		1×10^{12}	10^{14}	—	Ω

* All typical values are at Ta = 25°C (*1): Duration of I_O time ≤ 50μs

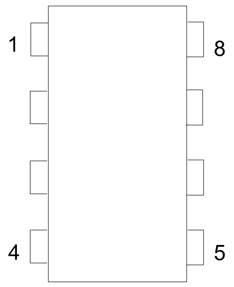
Switching Characteristics (Ta = −20~70°C , unless otherwise specified)

Characteristic		Symbol	Test Cir–cuit	Test Condition	Min.	Typ.*	Max.	Unit
Propagation delay time	L→H	t_{pLH}	6	I_F = 8mA (Note 7) V_{CC1} = +15V, V_{EE1} = −15V R_L = 200Ω	—	0.15	0.5	μs
	H→L	t_{pHL}			—	0.15	0.5	
Output rise time		t_r			—	—	—	
Output fall time		t_f			—	—	—	
Common mode transient immunity at high level output		C_{MH}	7	V_{CM} = 600V, I_F = 8mA V_{CC} = 30V, Ta = 25°C	−5000	—	—	V / μs
Common mode transient immunity at low level output		C_{ML}	7	V_{CM} = 600V, I_F = 0mA V_{CC} = 30V, Ta = 25°C	5000	—	—	V / μs

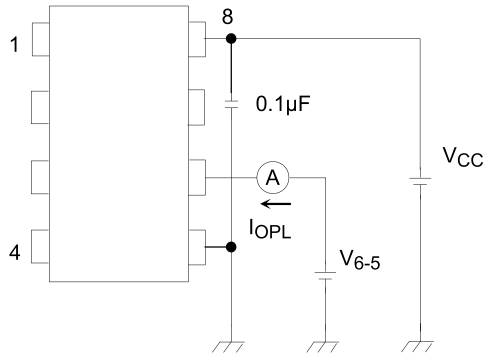
* All typical values are at Ta = 25°C

Note 7: Input signal rise time (fall time) < 0.5 μs.

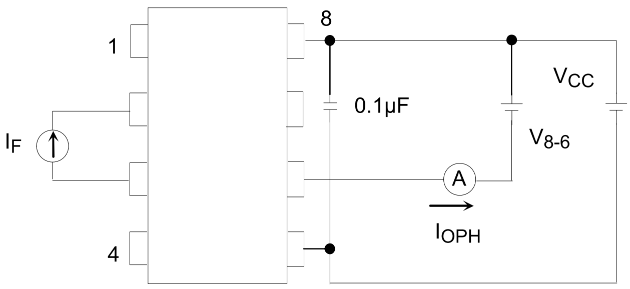
Test Circuit 1 :



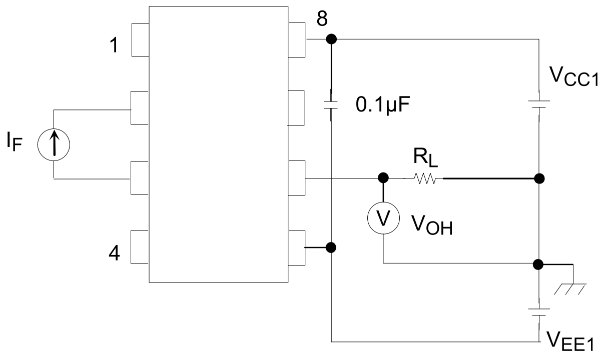
Test Circuit 2 : IOPL



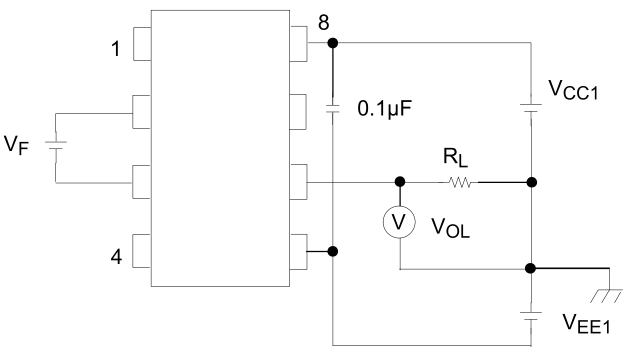
Test Circuit 3 : IOPH



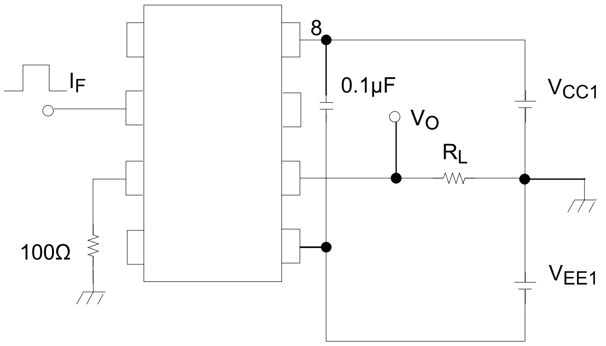
Test Circuit 4 : VOH

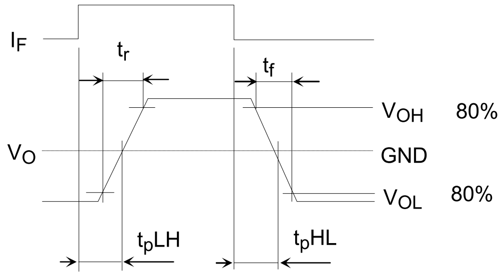


Test Circuit 5 : V_{OL}

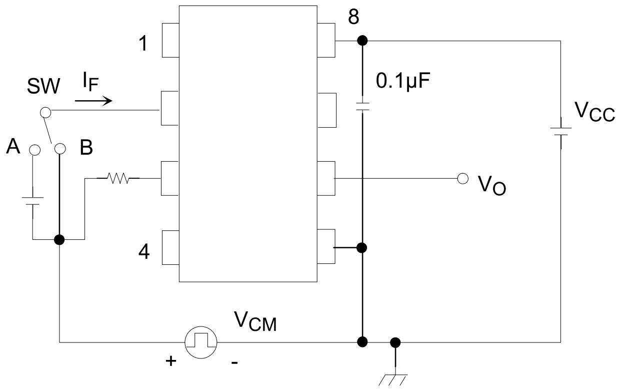


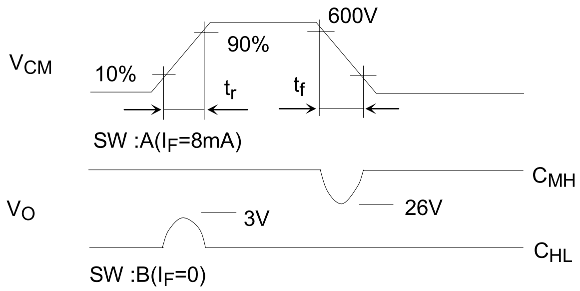
Test Circuit 6: t_{pLH}, t_{pHL}, t_r t_f





Test Circuit 7: C_{MH}, C_{ML}



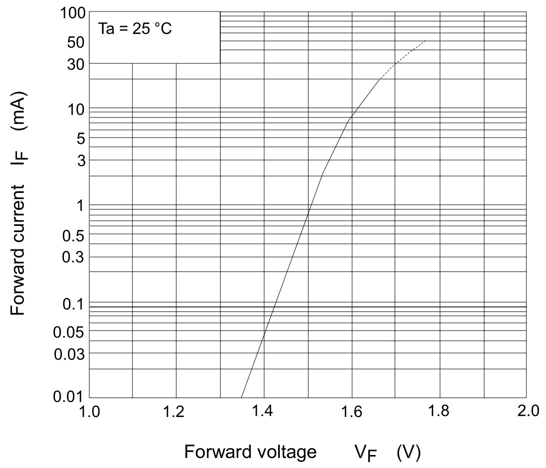


$$C_{ML} = \frac{480\ (V)}{t_r\ (\mu s)}$$

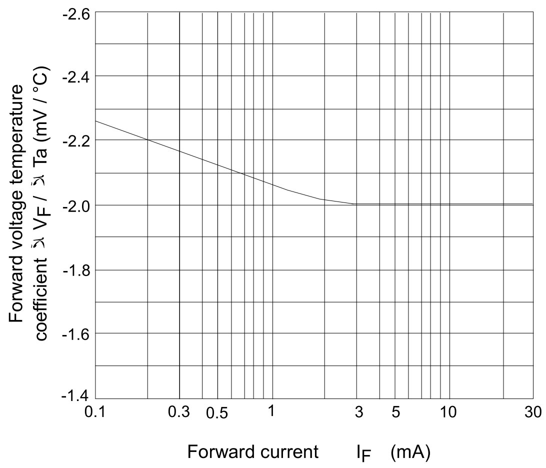
$$C_{MH} = \frac{480\ (V)}{t_f\ (\mu s)}$$

C_{ML}(C_{MH}) is the maximum rate of rise (fall) of the common mode voltage that can be sustained with the output voltage in the low (high) state.

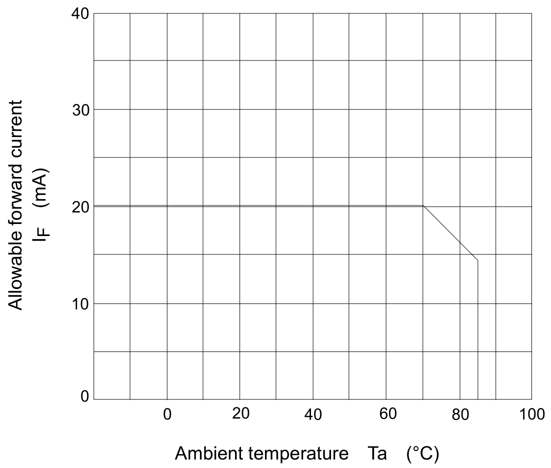
$I_F – V_F$



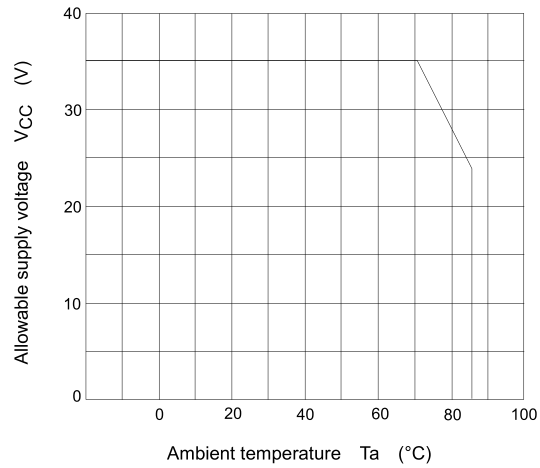
$ΔV_F / ΔTa – I_F$



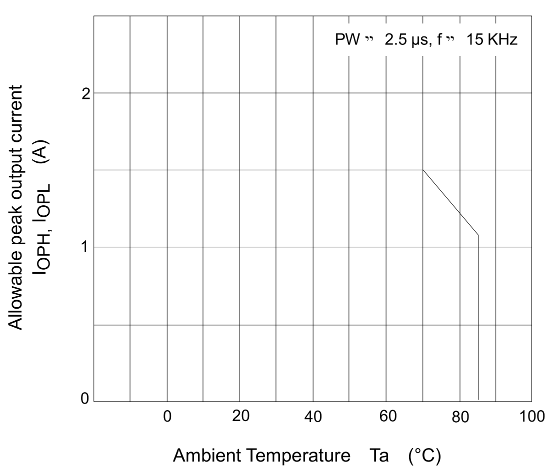
$I_F – Ta$



$V_{CC} – Ta$



$I_{OPH}, I_{OPL} – Ta$



RESTRICTIONS ON PRODUCT USE